

MITSUBISHI HIGH SPEED CMOS M74HC148P/FP/DP

8-LINE TO 3-LINE PRIORITY ENCODER

DESCRIPTION

The M74HC148 is a semiconductor integrated circuit consisting of an 8-line binary octal encoder with priority.

FEATURES

- Priority for data input
- Easily expandable number of input bits
- High-speed: 16ns typ. ($C_L=15\text{pF}$, $V_{CC}=5\text{V}$)
- Low power dissipation: $20\mu\text{W}/\text{package}$, max ($V_{CC}=5\text{V}$, $T_a=25^\circ\text{C}$, quiescent state)
- High noise margin: 30% of V_{CC} , min ($V_{CC}=4.5\text{V}$, 6V)
- Capable of driving 10 74LS TTL loads
- Wide operating voltage range: $V_{CC}=2\sim 6\text{V}$
- Wide operating temperature range: $T_a=-40\sim +85^\circ\text{C}$

APPLICATION

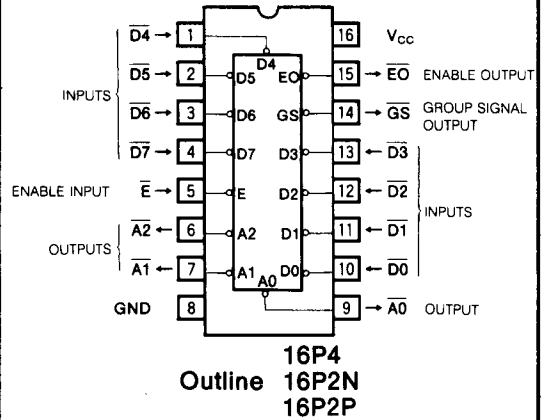
General purpose, for use in industrial and consumer digital equipment.

FUNCTIONAL DESCRIPTION

Use of silicon gate technology allows the M74HC148 to maintain the low power dissipation and high noise margin characteristics of the standard CMOS logic 4000B series while giving high-speed performance equivalent to the 74LS148.

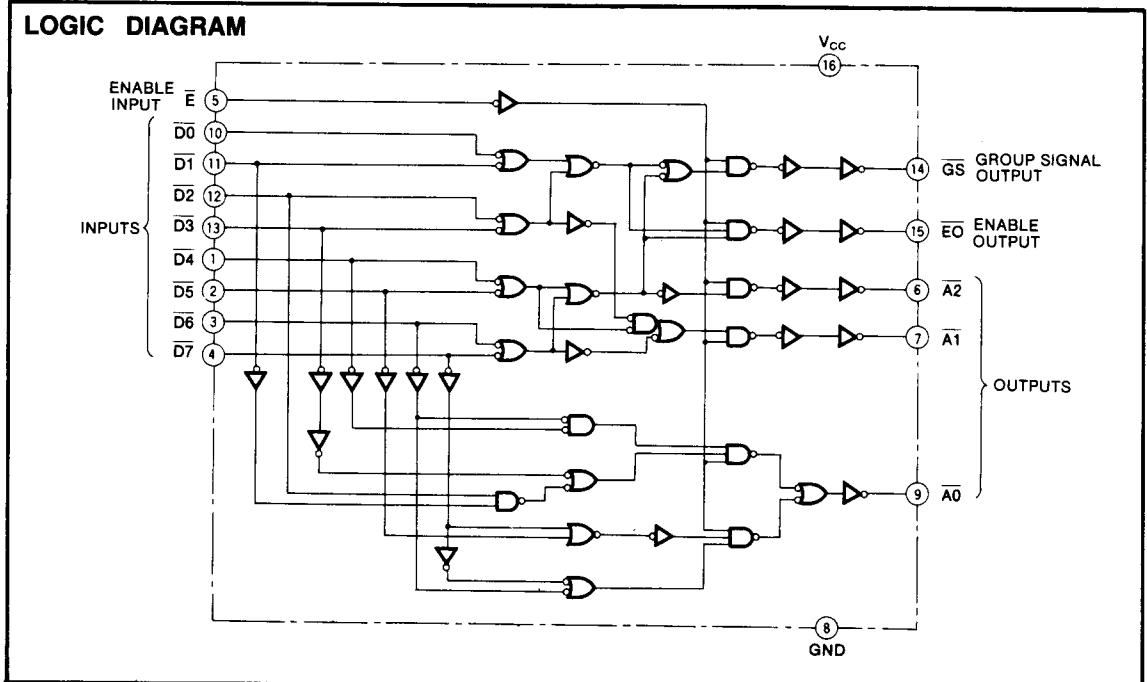
When an input is applied to one of the eight input lines $\overline{D0}$ through $\overline{D7}$, the corresponding 3-bit binary code is output at $\overline{A0}$ through $\overline{A2}$. When more than one input is applied simultaneously, the highest order pin is given priority. By using

PIN CONFIGURATION (TOP VIEW)



enable-input \overline{E} , enable-output \overline{EO} , and group-signal output \overline{GS} , the number of lines can be easily expanded, making the device ideal for keyboard encoders and range selectors.

LOGIC DIAGRAM



8-LINE TO 3-LINE PRIORITY ENCODER

FUNCTION TABLE (Note 1)

E	Inputs								Outputs				
	D0	D1	D2	D3	D4	D5	D6	D7	A2	A1	A0	GS	EO
H	X	X	X	X	X	X	X	X	H	H	H	H	H
L	H	H	H	H	H	H	H	H	H	H	H	H	L
L	X	X	X	X	X	X	X	L	L	L	L	L	H
L	X	X	X	X	X	X	L	H	L	L	H	L	H
L	X	X	X	X	X	L	H	H	L	H	L	L	H
L	X	X	X	L	H	H	H	H	L	H	L	L	H
L	X	X	L	H	H	H	H	H	H	L	H	L	H
L	X	L	H	H	H	H	H	H	H	H	L	L	H
L	L	H	H	H	H	H	H	H	H	H	H	L	H

Note 1 : X : Irrelevant

ABSOLUTE MAXIMUM RATINGS ($T_a = -40 \sim +85^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
V_{CC}	Supply voltage		$-0.5 \sim +7.0$	V
V_I	Input voltage		$-0.5 \sim V_{CC} + 0.5$	V
V_O	Output voltage		$-0.5 \sim V_{CC} + 0.5$	V
I_{IK}	Input protection diode current	$V_I < 0V$	-20	mA
		$V_I > V_{CC}$	20	
I_{OK}	Output parasitic diode current	$V_O < 0V$	-20	mA
		$V_O > V_{CC}$	20	
I_O	Output current per, output pin		± 25	mA
I_{CC}	Supply/GND current	V_{CC}, GND	± 50	mA
P_d	Power dissipation	(Note 2)	500	mW
T_{stg}	Storage temperature range		$-65 \sim +150$	$^\circ\text{C}$

Note 2 : M74HC148FP, $T_a = -40 \sim +70^\circ\text{C}$ and $T_a = 70 \sim 85^\circ\text{C}$ are derated at $-6\text{mW}/^\circ\text{C}$.
M74HC148DP, $T_a = -40 \sim +50^\circ\text{C}$ and $T_a = 50 \sim 85^\circ\text{C}$ are derated at $-5\text{mW}/^\circ\text{C}$.

RECOMMENDED OPERATING CONDITIONS ($T_a = -40 \sim +85^\circ\text{C}$)

Symbol	Parameter	Limits			Unit
		Min	Typ	Max	
V_{CC}	Supply voltage	2		6	V
V_I	Input voltage	0		V_{CC}	V
V_O	Output voltage	0		V_{CC}	V
T_{opr}	Operating temperature range	-40		+85	$^\circ\text{C}$
t_r, t_f	Input risetime, falltime	$V_{CC} = 2.0V$	0	1000	ns
		$V_{CC} = 4.5V$	0	500	
		$V_{CC} = 6.0V$	0	400	

8-LINE TO 3-LINE PRIORITY ENCODER

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits						Unit	
			V _{CC} (V)	25°C			-40~+85°C			
				Min	Typ	Max	Min	Max		
V _{IH}	High-level input voltage	V _O = 0.1V, V _{CC} = 0.1V I _O = 20μA	2.0 4.5 6.0	1.5 3.15 4.2			1.5 3.15 4.2		V	
V _{IL}	Low-level input voltage	V _O = 0.1V, V _{CC} = 0.1V I _O = 20μA	2.0 4.5 6.0			0.5 1.35 1.8		0.5 1.35 1.8	V	
V _{OH}	High-level output voltage	V _I = V _{IH} , V _{IL}	I _{OH} = -20μA	2.0	1.9			1.9		V
			I _{OH} = -20μA	4.5	4.4			4.4		
			I _{OH} = -20μA	6.0	5.9			5.9		
			I _{OH} = -4.0mA	4.5	4.18			4.13		
			I _{OH} = -5.2mA	6.0	5.68			5.63		
V _{OL}	Low-level output voltage	V _I = V _{IH} , V _{IL}	I _{OL} = 20μA	2.0				0.1		V
			I _{OL} = 20μA	4.5				0.1		
			I _{OL} = 20μA	6.0				0.1		
			I _{OL} = 4.0mA	4.5			0.26		0.33	
			I _{OL} = 5.2mA	6.0			0.26		0.33	
I _{IH}	High-level input current	V _I = 6V	6.0			0.1		1.0	μA	
I _{IL}	Low-level input current	V _I = 0V	6.0			-0.1		-1.0		
I _{CC}	Quiescent supply current	V _I = V _{CC} , GND, I _O = 0μA	6.0			4.0		40.0	μA	

SWITCHING CHARACTERISTICS (V_{CC} = 5V, T_a = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
t _{TLH}	Low-level to high-level and high-level to low-level output transition time	C _L = 15pF (Note 4)			10	ns
t _{THL}					10	
t _{PLH}	Low-level to high-level and high-level to low-level output propagation time (D0~D7 - A0~A2)				26	ns
t _{PHL}					26	
t _{PLH}	Low-level to high-level and high-level to low-level output propagation time (D0~D7 - E0, G5)				28	ns
t _{PHL}					28	
t _{PLH}	Low-level to high-level and high-level to low-level output propagation time (E - E0)				20	ns
t _{PHL}					20	
t _{PLH}	Low-level to high-level and high-level to low-level output propagation time (E - G5)				20	ns
t _{PHL}					20	
t _{PLH}	Low-level to high-level and high-level to low-level output propagation time (E - A0~A2)			21	ns	
t _{PHL}				21		

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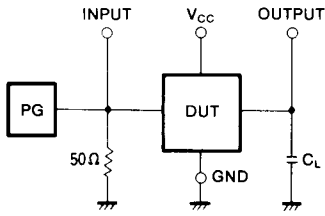
SWITCHING CHARACTERISTICS ($V_{CC} = 2\sim 6V$, $T_a = -40\sim +85^\circ C$)

Symbol	Parameter	Test conditions	Limits					Unit	
			$V_{CC}(V)$	25°C			-40~+85°C		
				Min	Typ	Max	Min		Max
t_{TLH}	Low-level to high-level and high-level to low-level		2.0			75		95	ns
			4.5			15		19	
			6.0			13		16	
t_{THL}	output transition time		2.0			75		95	ns
			4.5			15		19	
			6.0			13		16	
t_{PLH}	Low-level to high-level and high-level to low-level		2.0			150		190	ns
			4.5			30		38	
			6.0			26		33	
t_{PHL}	output propagation time ($\overline{D0}\sim\overline{D7} - \overline{A0}\sim\overline{A2}$)		2.0			150		190	ns
			4.5			30		38	
			6.0			26		33	
t_{PLH}	Low-level to high-level and high-level to low-level	$C_L = 50pF$ (Note 4)	2.0			165		205	ns
			4.5			33		41	
			6.0			28		35	
t_{PHL}	output propagation time ($\overline{D0}\sim\overline{D7} - \overline{E0}, \overline{GS}$)		2.0			165		205	ns
			4.5			33		41	
			6.0			28		35	
t_{PLH}	Low-level to high-level and high-level to low-level	$C_L = 50pF$ (Note 4)	2.0			120		150	ns
			4.5			24		30	
			6.0			20		26	
t_{PHL}	output propagation time ($\overline{E} - \overline{E0}$)		2.0			120		150	ns
			4.5			24		30	
			6.0			20		26	
t_{PLH}	Low-level to high-level and high-level to low-level	$C_L = 50pF$ (Note 4)	2.0			115		145	ns
			4.5			23		29	
			6.0			20		25	
t_{PHL}	output propagation time ($\overline{E} - \overline{GS}$)		2.0			115		145	ns
			4.5			23		29	
			6.0			20		25	
t_{PLH}	Low-level to high-level and high-level to low-level	$C_L = 50pF$ (Note 4)	2.0			125		155	ns
			4.5			25		31	
			6.0			21		26	
t_{PHL}	output propagation time ($\overline{E} - \overline{A0}\sim\overline{A2}$)		2.0			125		155	ns
			4.5			25		31	
			6.0			21		26	
C_i	Input capacitance						10	pF	
C_{PD}	Power dissipation capacitance (Note 3)						10	pF	

Note 3 : C_{PD} is the internal capacitance of the IC calculated from operation supply current under no-load conditions.
The power dissipated during operation under no-load conditions is calculated using the following formula:
 $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_1 + I_{CC} \cdot V_{CC}$

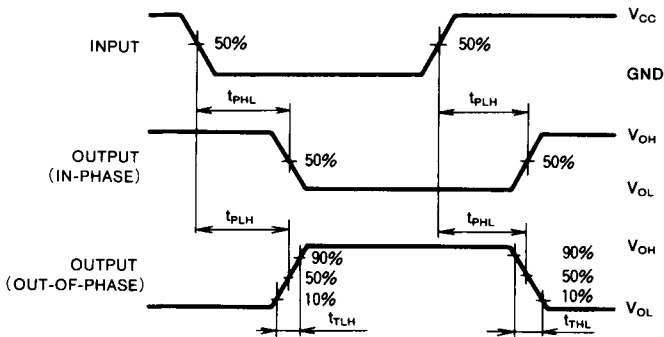
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Note 4 : Test Circuit



- (1) The pulse generator (PG) has the following characteristics (10%~90%): $t_r = 6\text{ns}$, $t_f = 6\text{ns}$
- (2) The capacitance C_L includes stray wiring capacitance and the probe input capacitance.

TIMING DIAGRAM



MITSUBISHI HIGH SPEED CMOS
PACKAGE OUTLINES

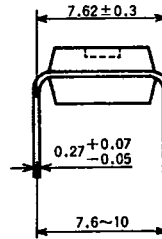
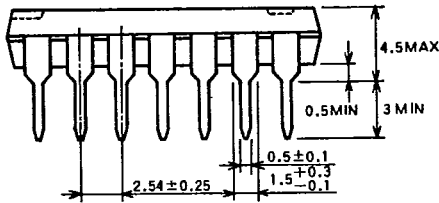
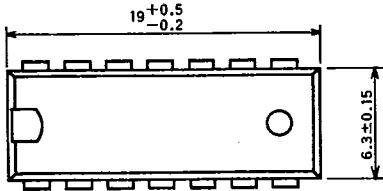
6249827 MITSUBISHI (DGTL LOGIC)

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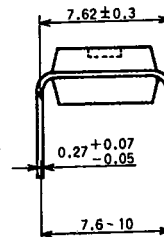
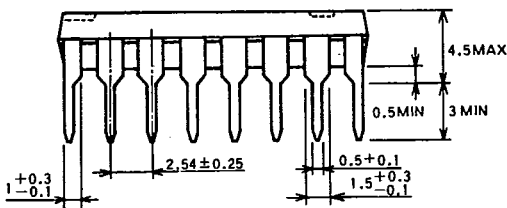
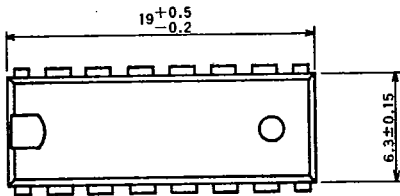
TYPE 14P4 14-PIN MOLDED PLASTIC DIP

Dimension in mm



TYPE 16P4 16-PIN MOLDED PLASTIC DIP

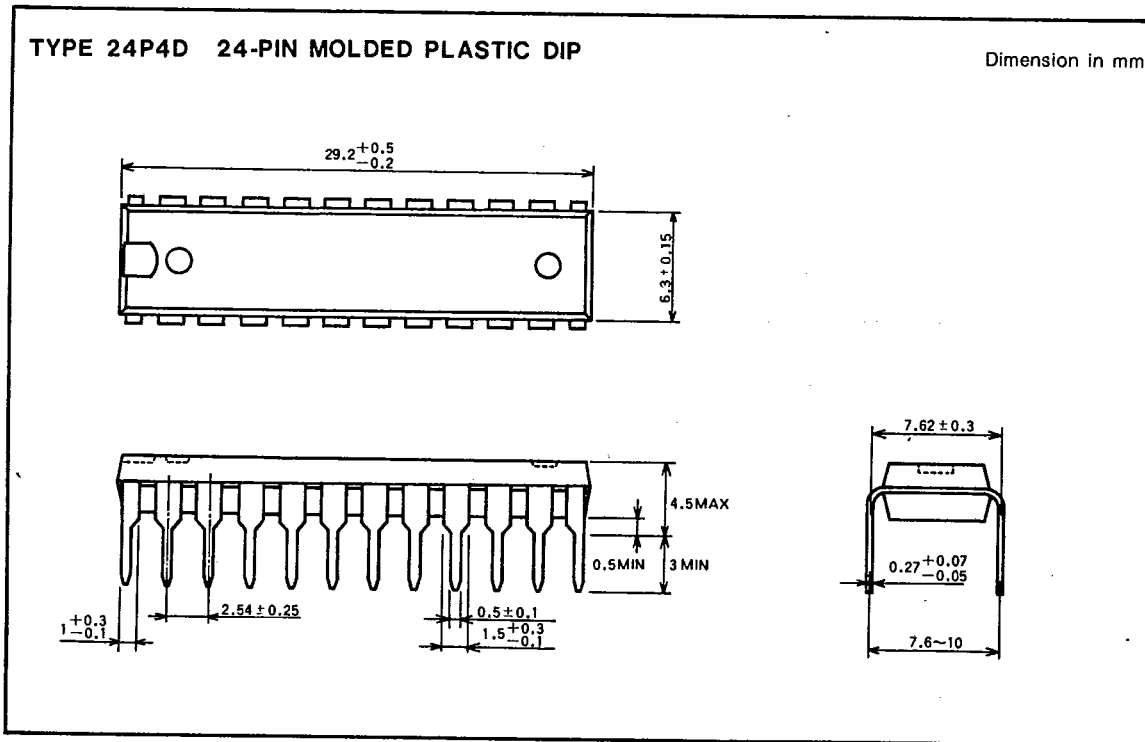
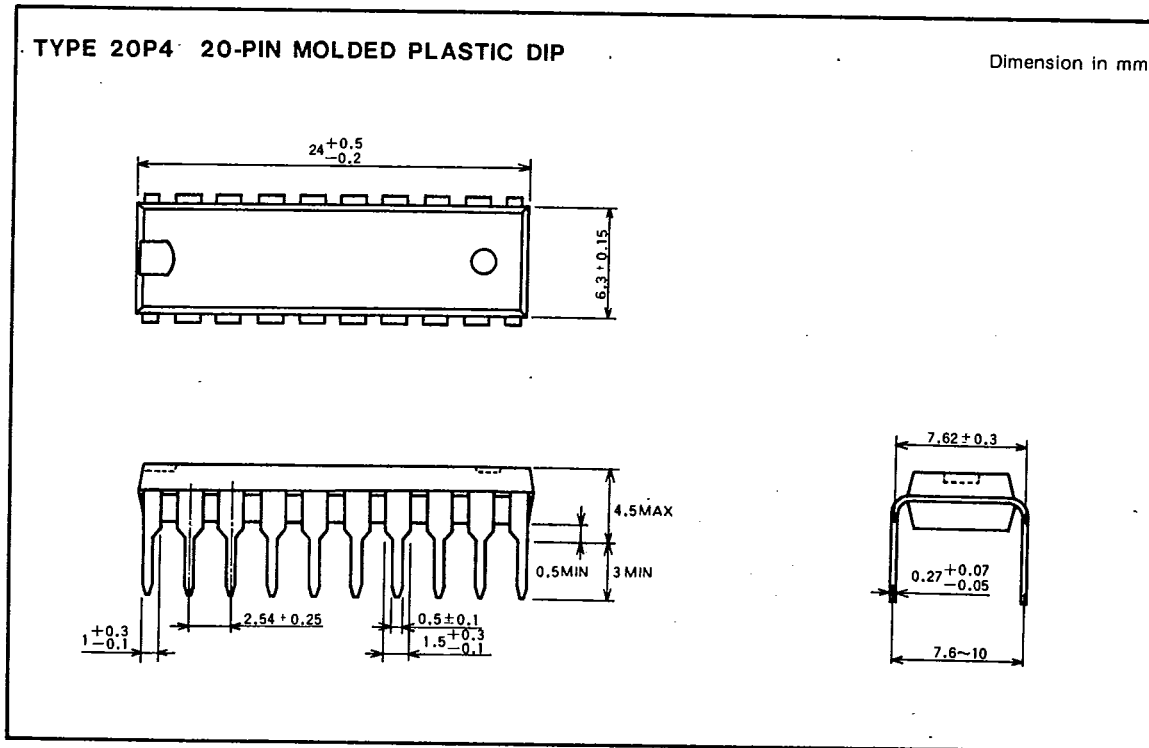
Dimension in mm



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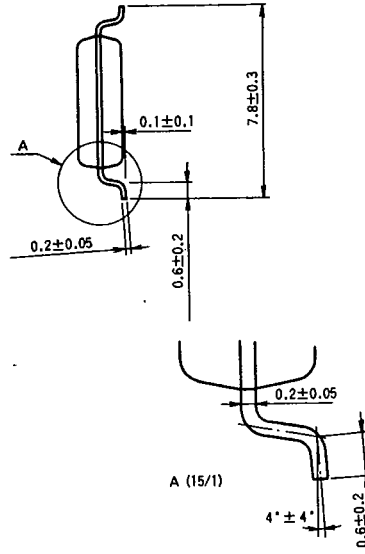
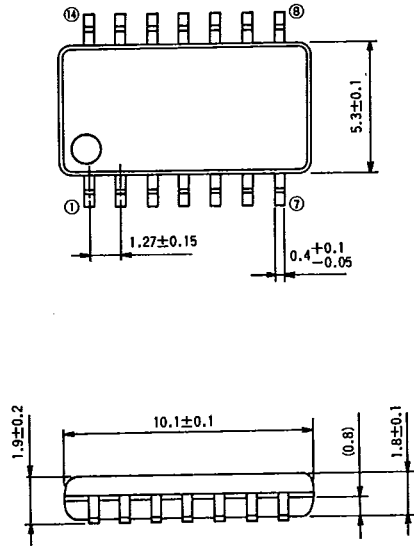
MITSUBISHI HIGH SPEED CMOS
PACKAGE OUTLINES

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91D 12851 D T-90.20

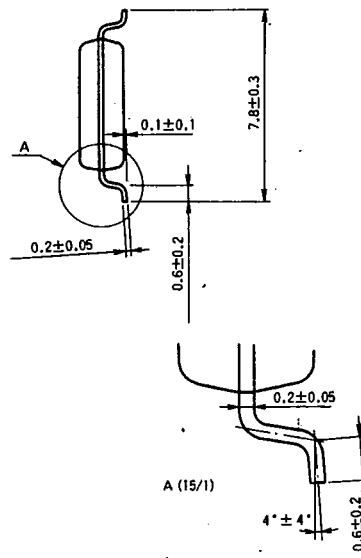
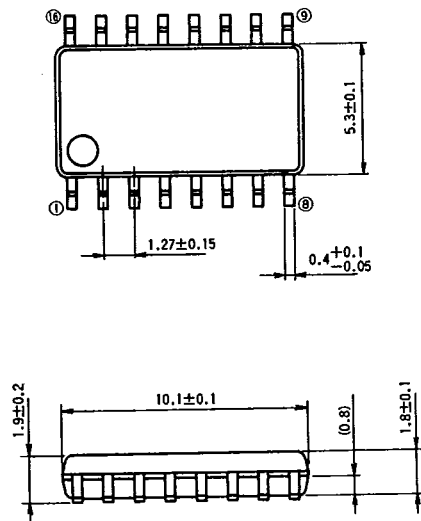
TYPE 14P2N 14PIN MOLDED PLASTIC SOP

Dimension in mm



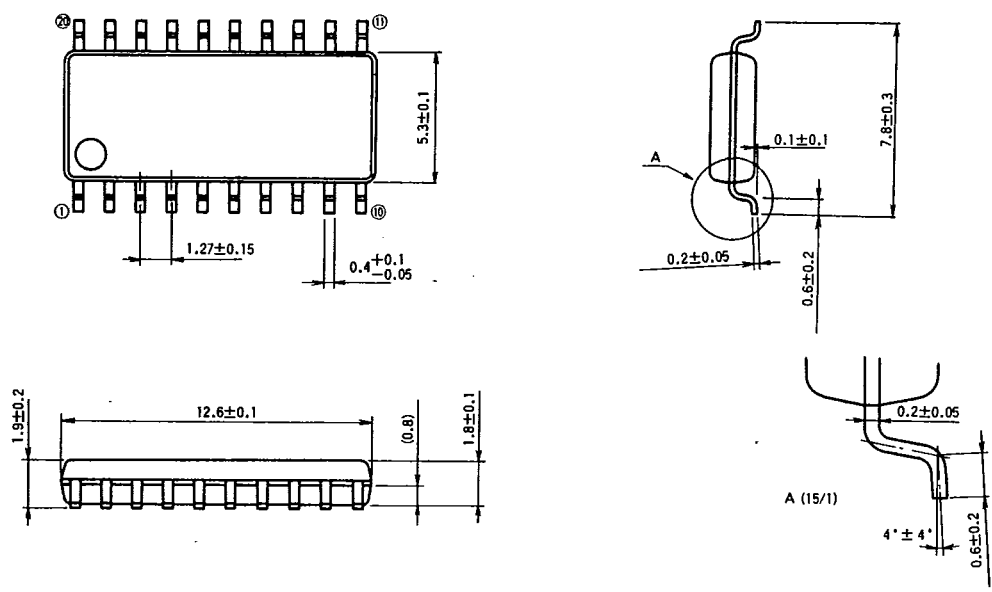
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Dimension in mm



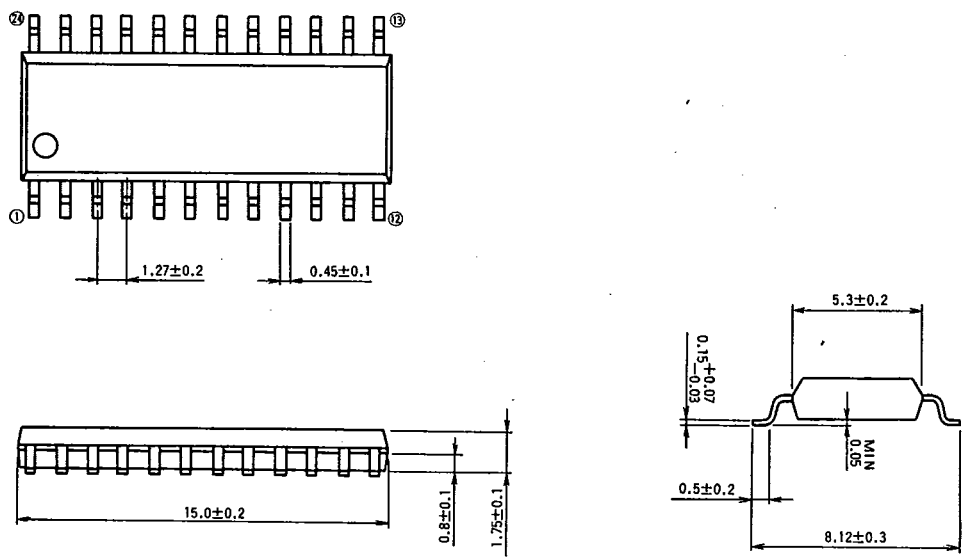
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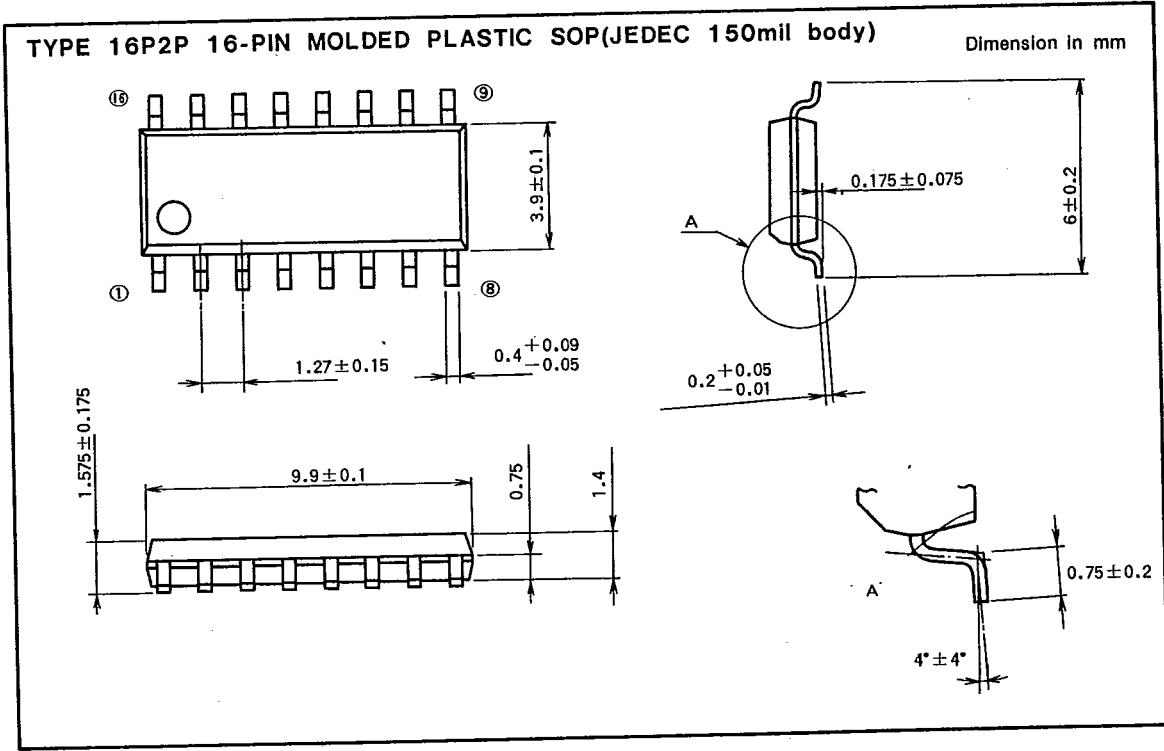
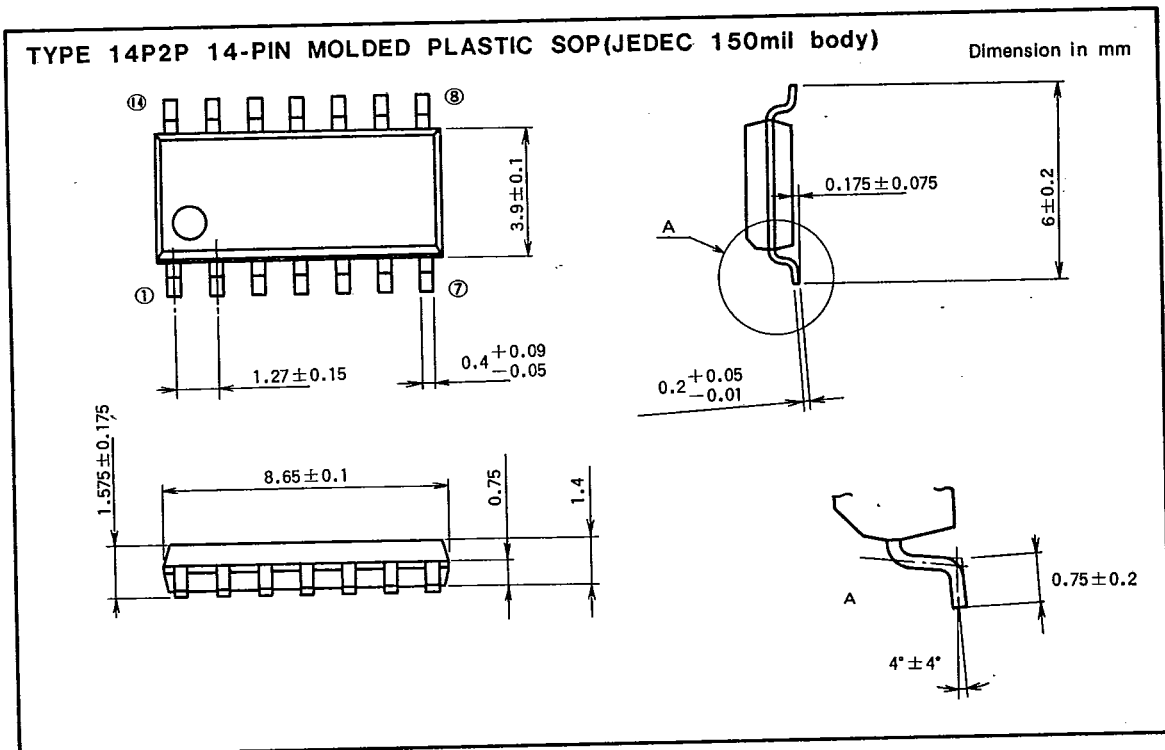
Dimension in mm



TYPE 24P2 24PIN MOLDED PLASTIC SOP

Dimension in mm





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